

江苏浩都频率科技有限公司

JIANGSU HD-CRYSTAL TECHNOLOGY CO., LTD

Specifications For Product

TYPE: Quartz Crystal Oscillator

SPEC: QMEMS7050/148.500M/3.3V/±30PPM

P/N : 8P148500301

VER: A/1

| R&D APPR. | SIGNATURED | | DEPT. |
|-----------|------------|----------|---|
| ISSUE | CHECK | APPROVAL | 新華科· 新華科· 新華科· 新華科· 新華科· 新華科· 新華科· 新華科· |
| 吴佳斌 | 微冰梯 | 主秋点 | 技术部 |

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Specification Revision Record Sheet

| Rev. | Revise page | Revise Contents | Date | Ref. No. | Reviser |
|------|-------------|------------------|-----------|----------|---------|
| A/0 | N/A | Initial released | 2018/3/30 | N/A | 吴佳斌 |
| A/1 | N/A | P/N revision | 2020/1/1 | N/A | 吴佳斌 |
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Product Descipion

8P148500301

- 1. Scope:
- 1.1 This specification applies to the RoHS crystal oscillator with a frequency of 148.500 MHz which will be used in electronic equipment.



- 2. Construction:
- 2.1 Oscillators series: QMEMS7050 8P series
- 2.2 Package: SMD 7.0×5.0

3.13 Output State Control:

3. Electrical Characteristics

| 3.1 | Nominal Frequency: | 148.500MHz |
|-----|----------------------|------------|
| 3.2 | Frequency Stability: | ±30ppm |

(incl. 25°C tolerance, tolerance over operating temperature range, input voltage change, load change, 1 year aging)

| 3.3 | Aging: | ±3ppm/year Max |
|-----|-----------------------------------|----------------|
| 3.4 | Operating Temperature Range: | -40 to + 85°C |
| 3.5 | Storage Temperature Range: | -55 to +125°C |
| 3.6 | Input Voltage (V _{DD}): | +3.3Vdc±10% |

- 3.7 Input Current (I_{DD}): 36mA max
- 3.8 Output Waveform: CMOS
- 3.9 Output Symmetry: 45%~55%
- 3.10 Rise/Fall Time: 5ns max
- 3.11 Output Voltage V_{OL} : 10%VDD
 - V_{OH}: 90%VDD
- 3.12 Output Load: 15pF
- 3.14 Start-up Time: 5ms max3.15 Standby current: 10μA max
- 3.16 Phase Jitter (rms): 1ps rms max 12kHz to 20MHz max

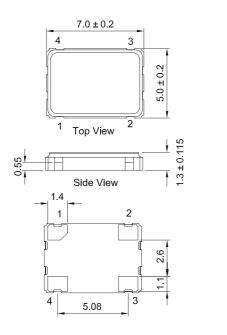
Enable/disable

- 3.17 Oscillation mode: Fundmental
- 3.18 Others: Not recommended for safety applications

Reliability Specification

| NO. | ITEM | SPECIFICATION | TEST METHOD |
|------|---|--|--|
| 4.1 | Temperature Cycle (GB/T 2423.22-2002, Method Nb) | Frequency change after test≤± 5ppm. | 10 cycles from -55°C to 125°C. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.2 | Low Temperature Storage (GB/T 2423.1-2001, Method Aa) | Frequency change after test≤± 5ppm. | Spending 72 hrs at -55°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.3 | High Temperature Storage (GB/T 2423.2-2001, Method Ba) | Frequency change after test≤± 5ppm. | Spending 72 hrs at 125°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.4 | Humidity (GB/T 2423.3- 2006, Method Cab) | Frequency change after test≤± 5ppm. | Spending 96 hrs at 40 °C ± 3 °C, with 90± 3% R.H. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.5 | Vibration (GB/T 2423.10- 1995, Method Fc) | Frequency change after test≤± 5ppm. | Apply 0.75mm vibration at sweep frequency $10\sim500$ Hz, for 2h. 10 cycles in each direction of 3 axis. Measurement taken after 1 hour. |
| 4.6 | Shock (GB/T 2423.5-1995, Method Ea) | Frequency change after test≤± 5ppm. No visible damages. | Peak 1000m/s2, normal width 6ms half sine wave form, 3.7m/s, 3 perpendicular axis of samples, 3 cycles / direction, total 18 cycles. Measurement taken after 1 hour. |
| 4.7 | Drop (GB/T 2423.8-1995, Method Ed) | Frequency change after test≤± 5ppm. No visible damages. | Free drop to the wooden plate from 1.0 m heights for 3 times. |
| 4.8 | Solderability (GB/T 2423.28-2005, Method Tc) | Terminals shall be covered more then 95% with solder. | In 245 \pm 5 $^{\circ}\mathrm{C}$ solder bath for 2 \pm 0.5 seconds. There is no need to do functioned test. 8-12X magnifier. |
| 4.9 | Terminal Strength (JIS-C-6429 Method 1 & 2) | No visible damage | Mount on a glass-epoxy board (100x50x1.6mm), then bend to 2mm displacement (velocity 1mm/sec) and keep for 5 seconds. or pulling force 0.5 kg for at least 60 seconds. |
| 4.10 | Resistance to Soldering Heat (GB/T 2423.28-2005, Test Tb Method 1B) | Frequency change after test≤± 5ppm. | Passed through the re-flow oven under the following condition. Preheat to 150°C±5°C for 60 to 120sec,and peak 265°C±5°C for 10s±3sec.Measurement taken after DUT being left at room temperature for at 24±2 hours. |
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| 4.11 | OTHERS | | |

Package Outline Dimensions



PAD FUNCTION:

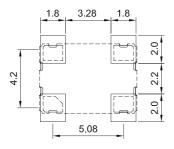
1: ENABLE CONTROL

2: GND

3: OUT

4: VDD

Suggested Pad Layout



Packing Specification

